

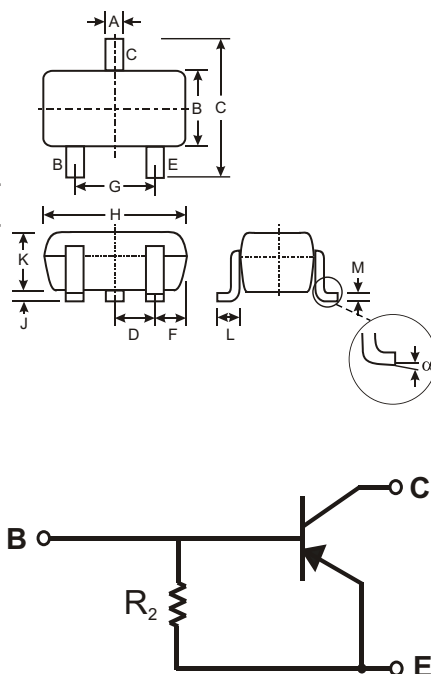
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTC)
- Built-In Biasing Resistor, R2 only
- Also Available in Lead Free Version

Mechanical Data

- Case: SOT-323, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 3, on Page 2
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 2)

P/N	R2 (NOM)	MARKING
DDTA114GUA	10K Ω	P26
DDTA124GUA	22K Ω	P27
DDTA144GUA	47K Ω	P28
DDTA115GUA	100K Ω	P29



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
α	0°	8°
All Dimensions in mm		

SCHEMATIC DIAGRAM

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C (Max)	-100	mA
Power Dissipation	P_d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Operating and Storage and Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

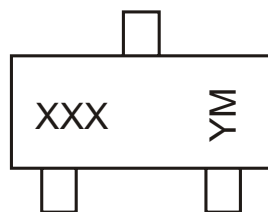
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_{CBO}	-50	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage		BV_{CEO}	-50	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage		BV_{EBO}	5	—	—	V	$I_E = -720\mu\text{A}$, DDTA114GUA $I_E = -330\mu\text{A}$, DDTA124GUA $I_E = -160\mu\text{A}$, DDTA144GUA $I_E = -72\mu\text{A}$, DDTA115GUA
Collector Cutoff Current		I_{CBO}	—	—	-0.5	μA	$V_{CB} = -50\text{V}$
Emitter Cutoff Current	DDTA114GUA DDTA124GUA DDTA144GUA DDTA115GUA	I_{EBO}	-300 -140 -65 -30	—	-580 -260 -130 -58	μA	$V_{EB} = -4\text{V}$
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	—	—	-0.3	V	$I_C = -10\text{mA}$, $I_B = -0.5\text{mA}$
DC Current Transfer Ratio	DDTA114GUA DDTA124GUA DDTA144GUA DDTA115GUA	h_{FE}	30 56 68 82	—	—	—	$I_C = -5\text{mA}$, $V_{CE} = -5\text{V}$
Bleeder Resistor (R_2) Tolerance		DR_2	-30	—	+30	%	—
Gain-Bandwidth Product*		f_T	—	250	—	MHz	$V_{CE} = -10\text{V}$, $I_E = 5\text{mA}$, $f = 100\text{MHz}$

* Transistor - For Reference Only

Ordering Information (Note 2)

Device	Packaging	Shipping
DDTA114GUA-7	SOT-323	3000/Tape & Reel
DDTA124GUA-7	SOT-323	3000/Tape & Reel
DDTA144GUA-7	SOT-323	3000/Tape & Reel
DDTA115GUA-7	SOT-323	3000/Tape & Reel

- Notes: 2. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
3. For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above.
Example: DDTA115GUA-7-F.

Marking Information


XXX = Product Type Marking Code
See Sheet 1 Diagrams
YM = Date Code Marking
Y = Year ex: N = 2002
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

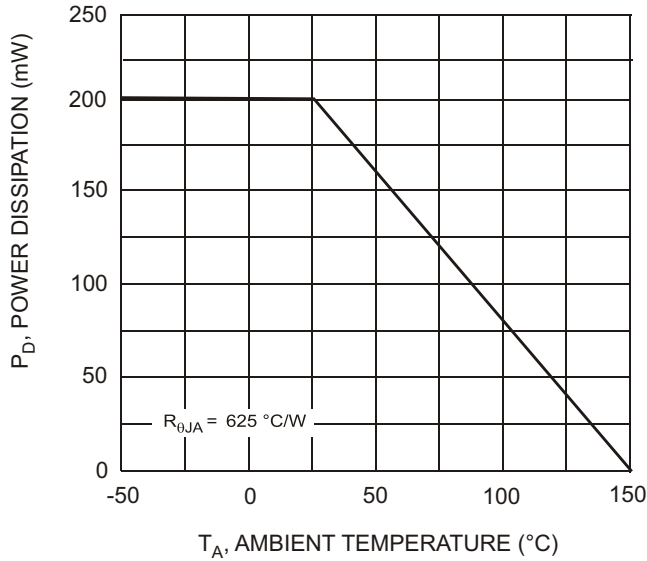
TYPICAL CURVES - DDTA114GUA
NEW PRODUCT


Fig. 1, Derating Curve

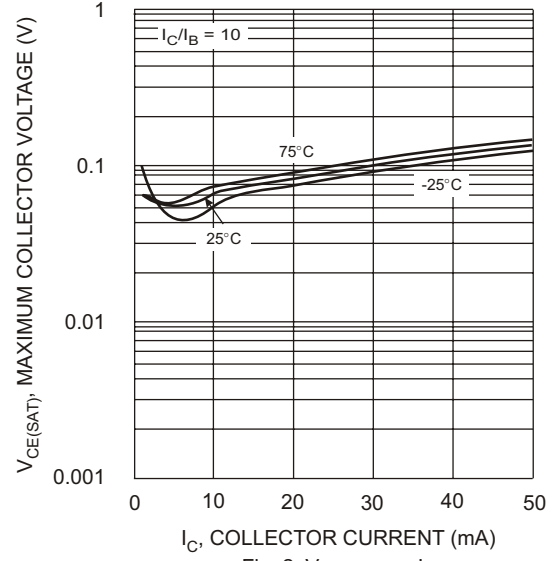
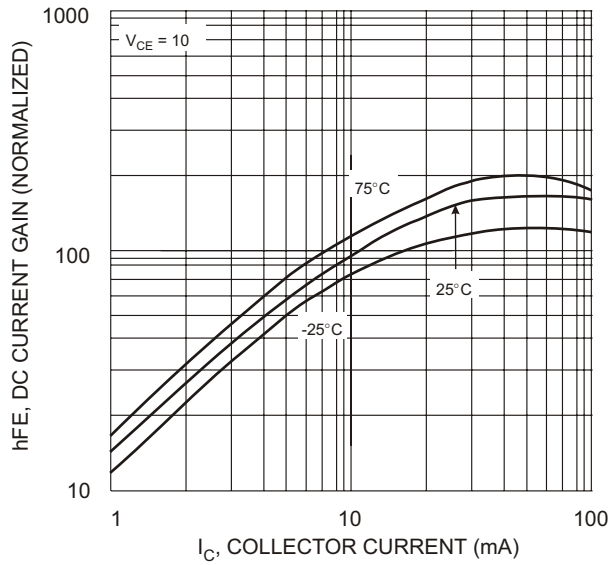

 Fig. 2 $V_{CE(SAT)}$ vs. I_C


Fig. 3 DC Current Gain

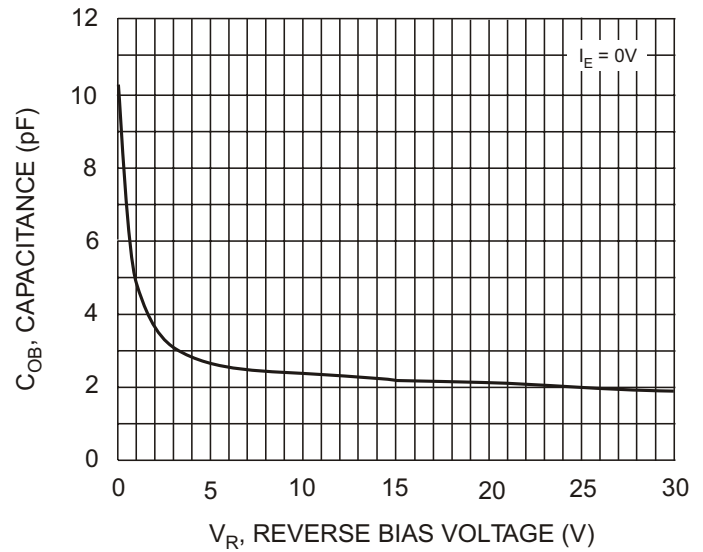


Fig. 4 Output Capacitance

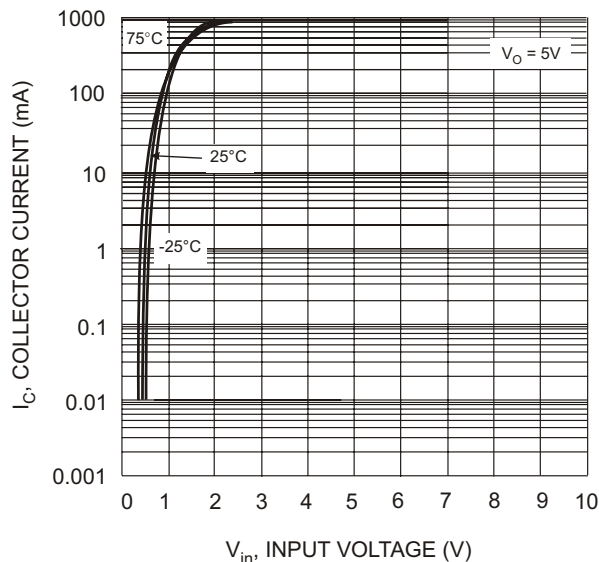


Fig. 5 Collector Current Vs. Input Voltage

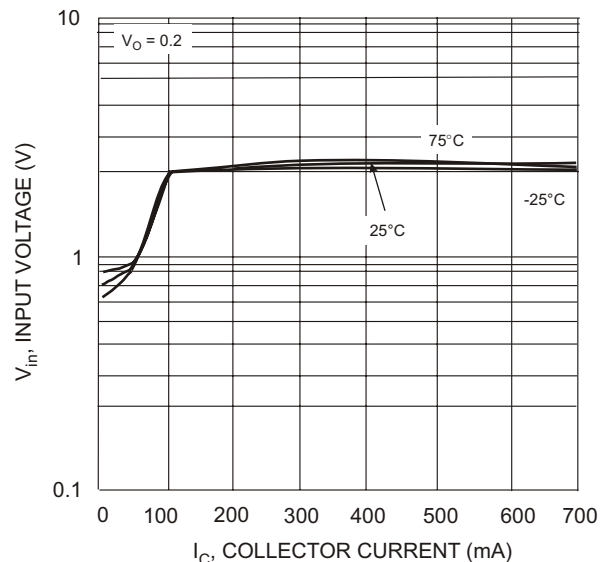


Fig. 6 Input Voltage vs. Collector Current